



INTERNATIONAL ATOMIC ENERGY AGENCY
UNITED NATIONS EDUCATIONAL, SCIENTIFIC AND CULTURAL ORGANIZATION
INTERNATIONAL CENTRE FOR THEORETICAL PHYSICS
I.C.T.P., P.O. BOX 586, 34100 TRIESTE, ITALY, CABLE: CENTRATOM TRIESTE



H4.SMR/453-30

**TRAINING COLLEGE ON
PHYSICS AND CHARACTERIZATION
OF LASERS AND OPTICAL FIBRES**

(5 February - 2 March 1990)

SOLID STATE LASERS

P. Mazzinghi

**Institute for Quantum Electronics
Florence, Italy**

SOLID STATE LASERS

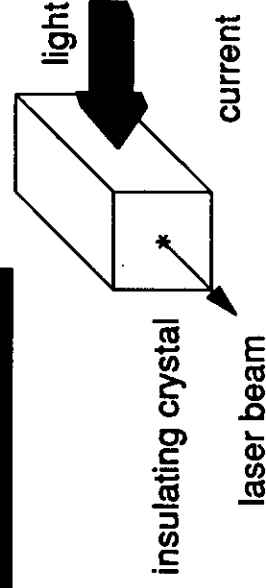
P. Mazzinghi

Istituto di Elettronica Quantistica
Firenze, Italy

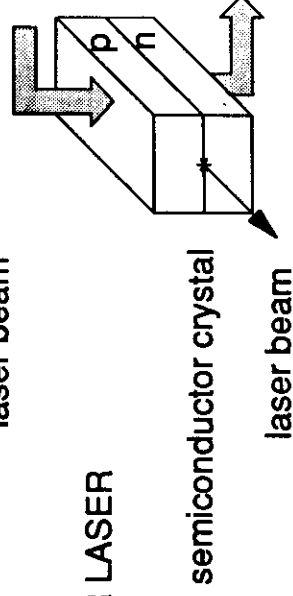
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DEFINITION

□ SOLID STATE LASER



□ SEMICONDUCTOR LASER



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SOLID STATE LASER MATERIALS

● HOST MATERIALS

- glasses (Nd:glass)
- crystals (sapphire, garnets)

● ACTIVE IONS

- rare earth (Nd, Er, Ho)
- transition metals (Cr, Ti)

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HOST MATERIALS

● GLASSES

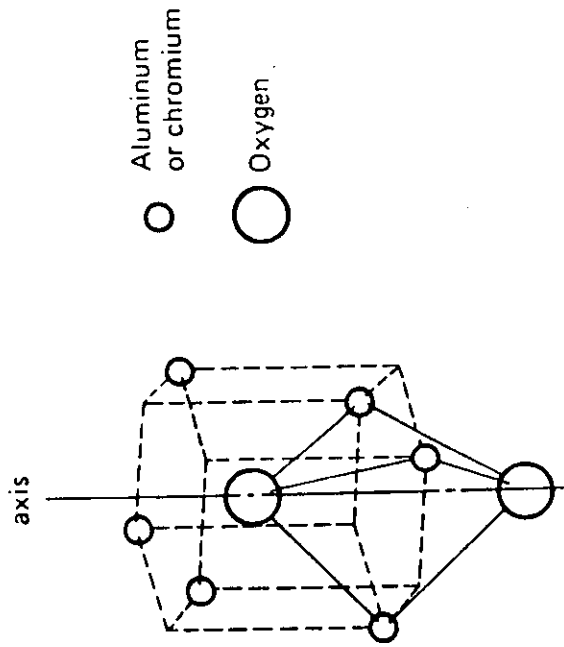
- advantages:
 - good optical quality
 - available in large size
 - low cost
- disadvantages:
 - low thermal conductivity

● CRYSTALS

- advantages:
 - high thermal conductivity
 - good mechanical properties
- disadvantages:
 - available in small size
 - high cost

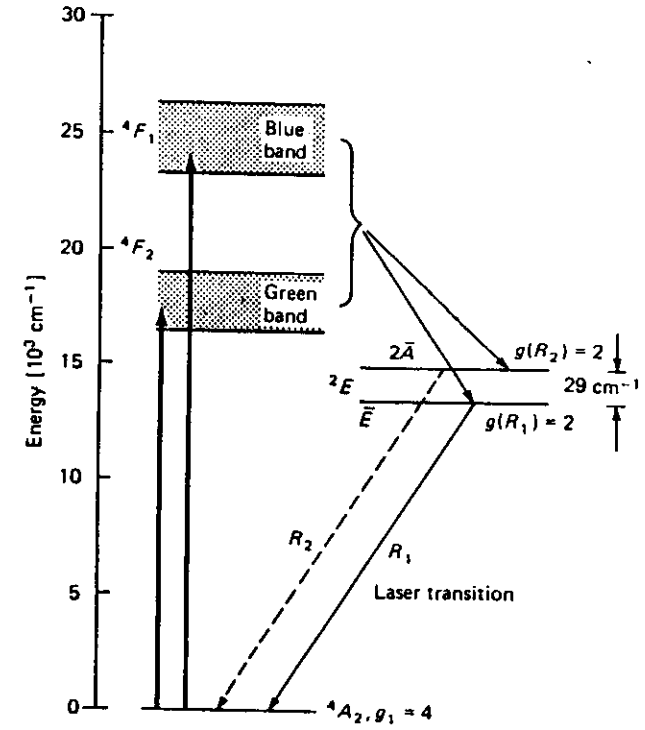
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CRYSTAL STRUCTURE OF SAPPHIRE



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ENERGY LEVELS OF RUBY



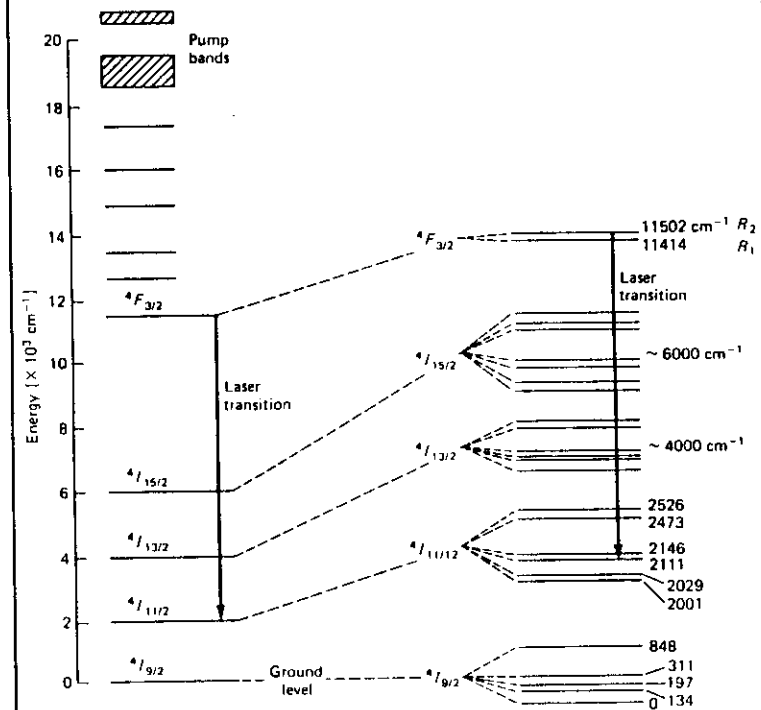
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LASER PROPERTIES OF RUBY

Chemical formula	Cr:Al ₂ O ₃
Cr doping	1.58E19 ions cm ⁻³
Emission wavelengths	694.3, 692.9 nm
Fluorescent lifetime	3.0 ms
Emission linewidth	0.53 nm
Quantum efficiency	70 %
Refractive index	1.76
Thermal conductivity	0.42 W/cm/K

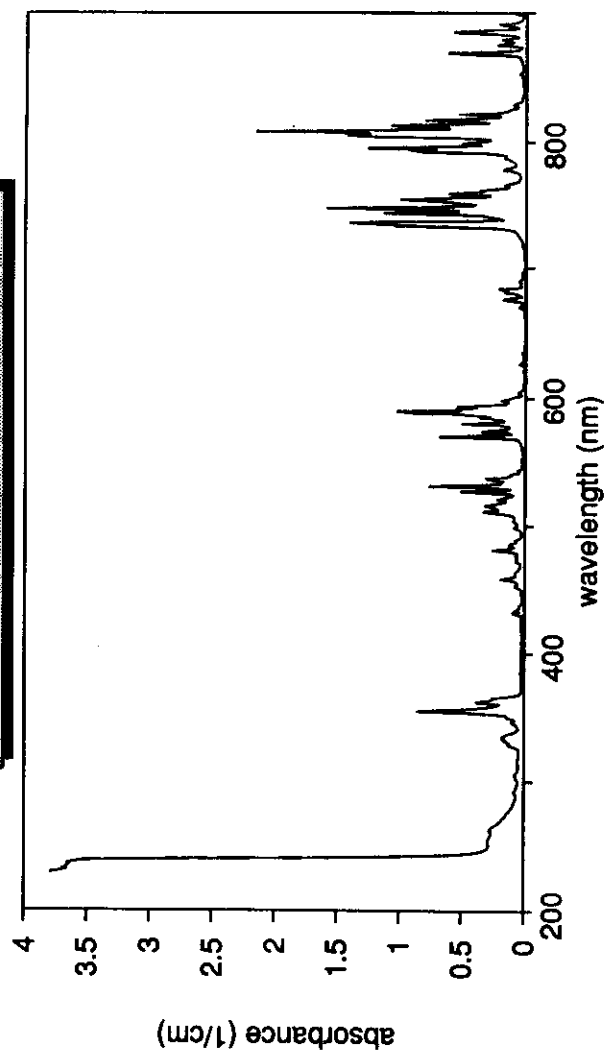
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ENERGY LEVELS OF Nd:YAG



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Nd:YAG ABSORPTION



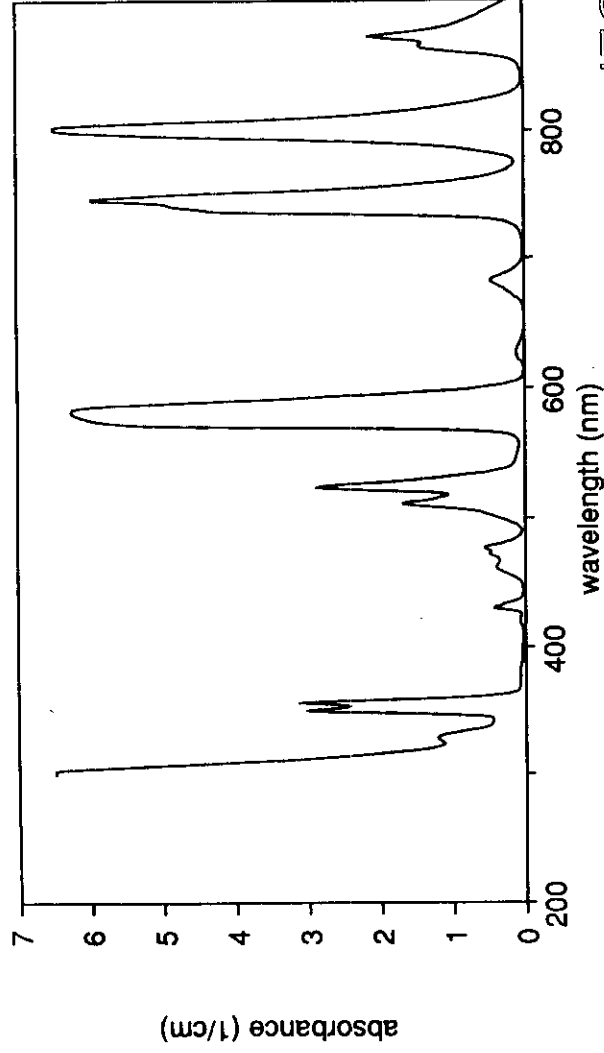
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LASER PROPERTIES OF Nd:YAG

Chemical formula	$\text{Nd:Y}_3\text{Al}_5\text{O}_{12}$
Nd doping	$1.38\text{E}20 \text{ ions cm}^{-3}$
Emission wavelengths	1.06414 μm
Fluorescent lifetime	0.23 ms
Emission linewidth	0.45 nm
Quantum efficiency	99.5 %
Refractive index	1.82
Thermal conductivity	0.13 W/cm/K

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Nd:GLASS ABSORPTION



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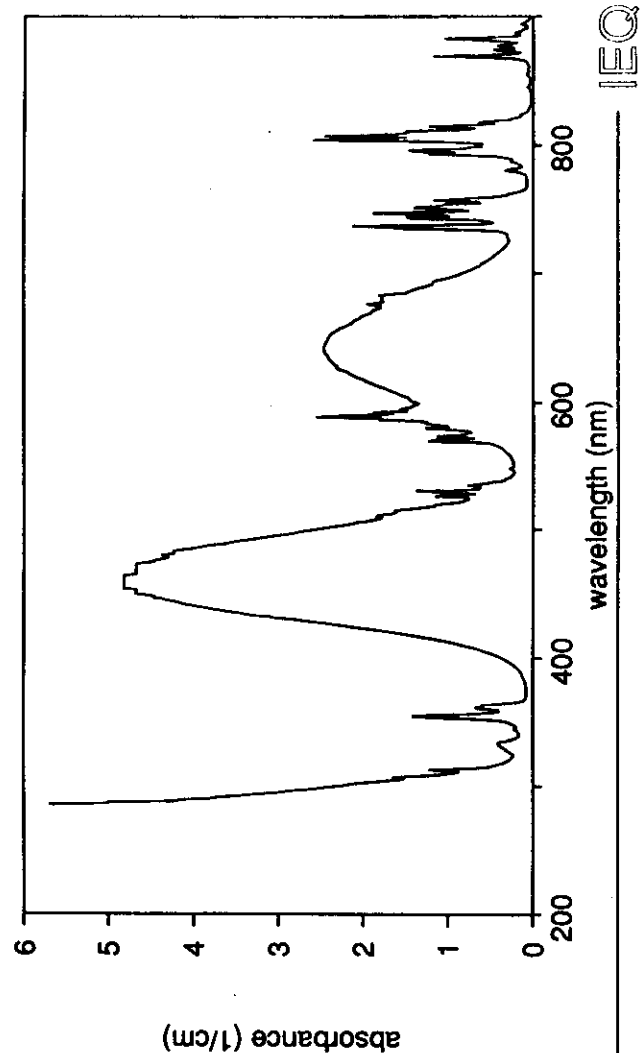
PROPERTIES OF LASER GLASSES

Property:	LG-680 Silicate	APG-1 Phosphate	LG-750 Phosphate	LG-760 Phosphate
Refractive Index at Laser Wavelength	1.560	1.526	1.516	1.508
Refractive Index at 587.56 nm	1.570	1.535	1.526	1.519
Abbe Number	57.7	67.6	68.2	69.2
Laser Wavelength (nm)	1061	1052	1053.5	1053.5
Cross Section (10^{-20} cm^2)	2.9	3.5	4.0	4.2
Fluorescence Lifetime (μsec)	>350	>360	>360	>350
Non-linear Refractive Index (10^{-13} esu)	1.60	1.12	1.08	1.02
Temp. Coeff. Refractive Index ($10^{-6}/\text{K}$)	2.9	1.2	-5.1	-6.8
Temp. Coeff. Optical Path ($10^{-6}/\text{K}$)	8.1	5.2	0.8	0.4
Density (g/cm^3)	2.54	2.64	2.83	2.60
Elastic Modulus (1000 N/mm^2)	90.2	71.0	50.1	53.7
Poisson's Ratio	0.242	0.239	0.256	0.267
Thermal Expansion Coeff., 20-40°C	93	76	114	125
Thermal Conductivity (w/mK)	1.35	0.83	0.62	0.67
Pt-free?	no	yes	yes	yes
FCM*	1.22	1.37	0.81	0.73

*FCM = $K(1-\nu)/E$, excluding fracture toughness, S.

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Nd,Cr:GSGG ABSORPTION



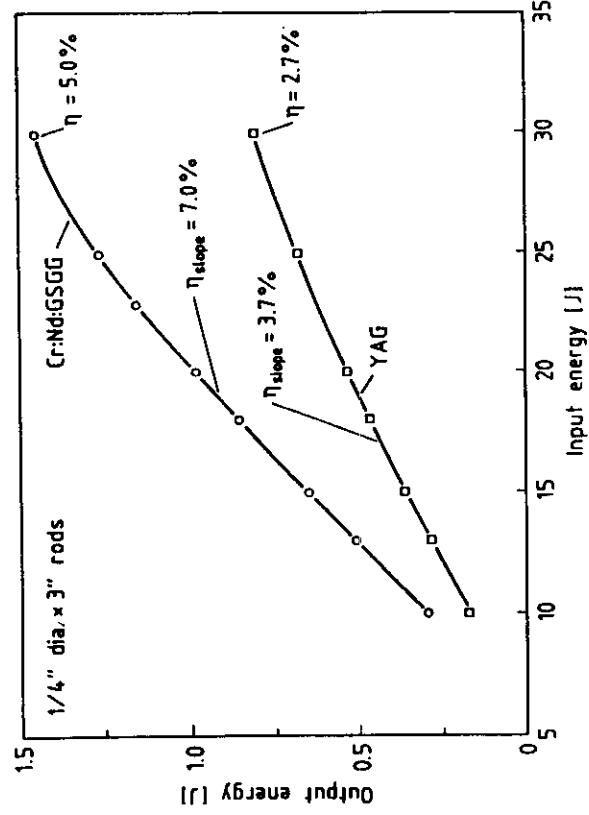
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LASER PROPERTIES OF Nd,Cr:GSGG

Chemical formula	Nd,Cr:Gd ₃ Sc ₂ Ga ₃ O ₁₂
Nd doping	1.6 %
Cr doping	2.5 %
Emission wavelengths	1061.2 nm
Fluorescent lifetime	0.24 ms
Emission linewidth	0.5 nm
Quantum efficiency	90 %
Refractive index	1.95
Thermal conductivity	0.06 W/cm/K

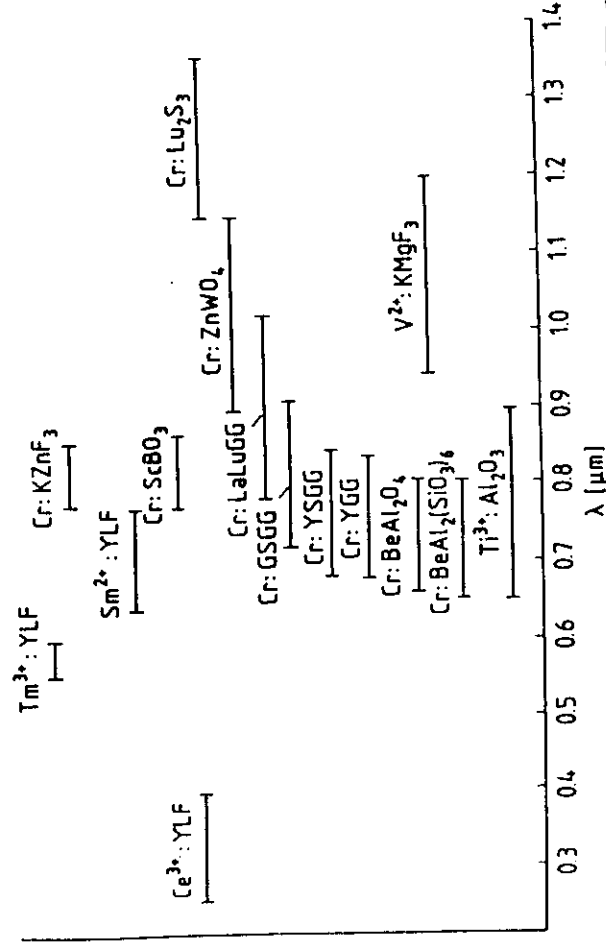
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EFFICIENCY OF YAG AND GSGG

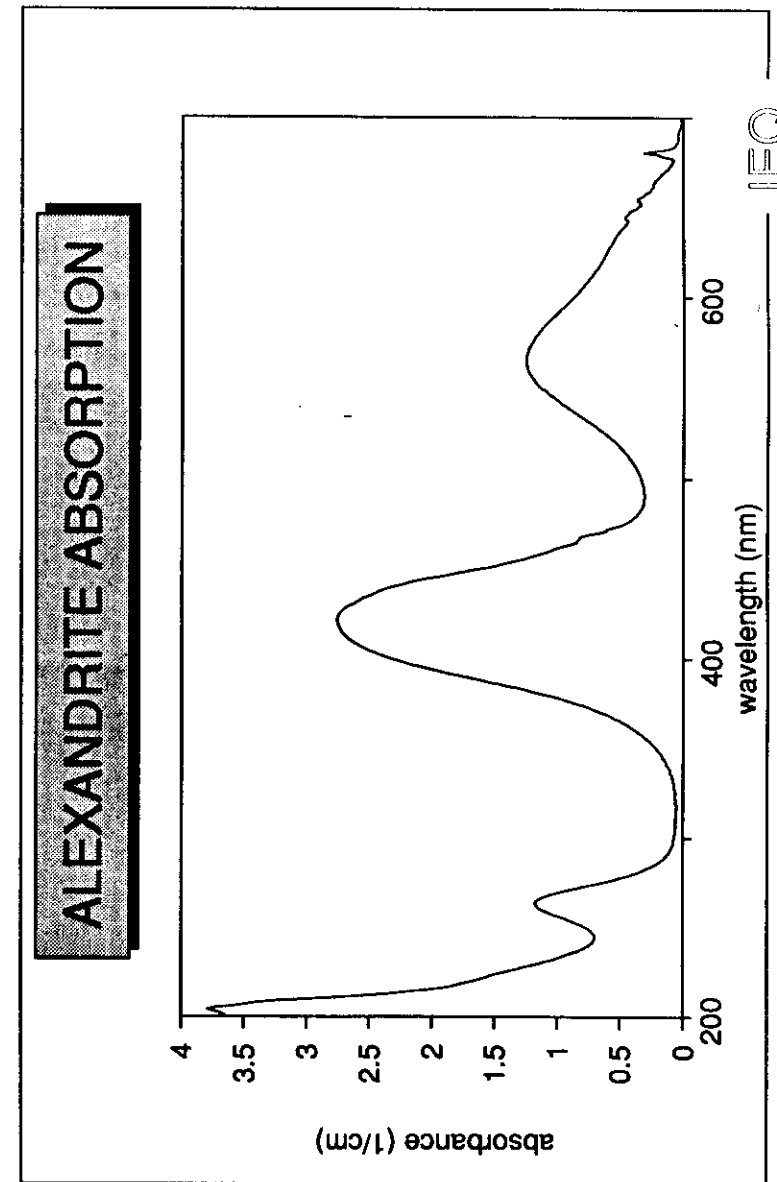
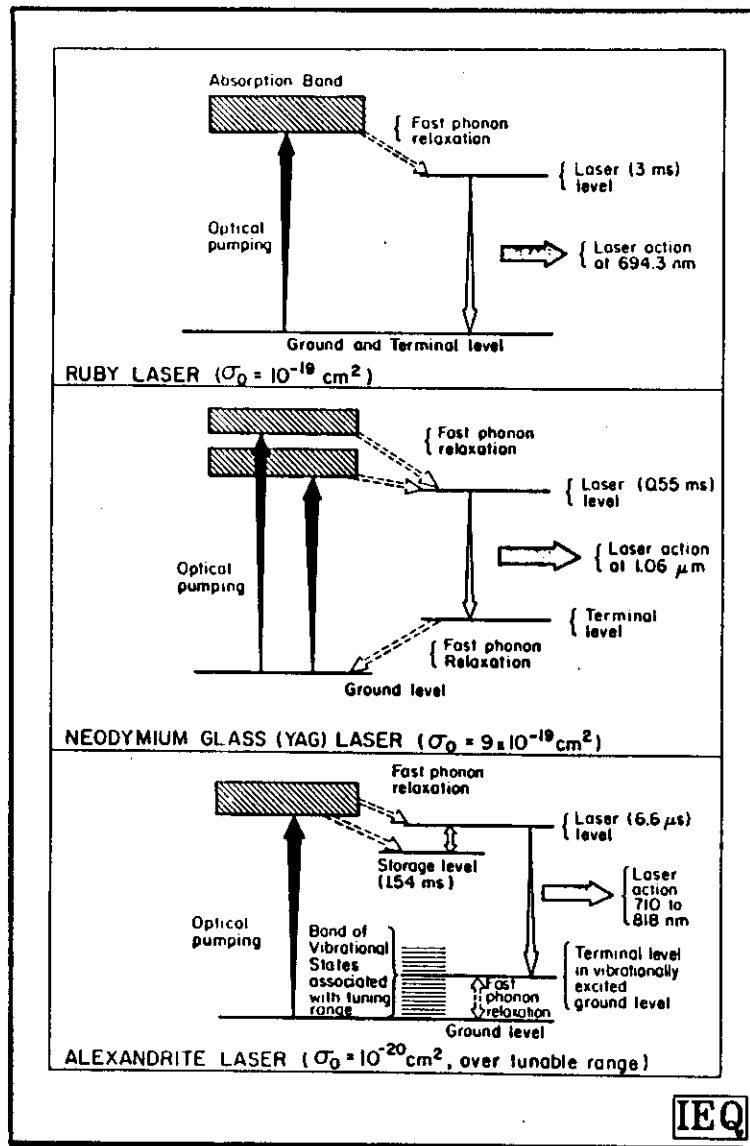


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TUNABLE RANGE OF VIBRONIC LASERS



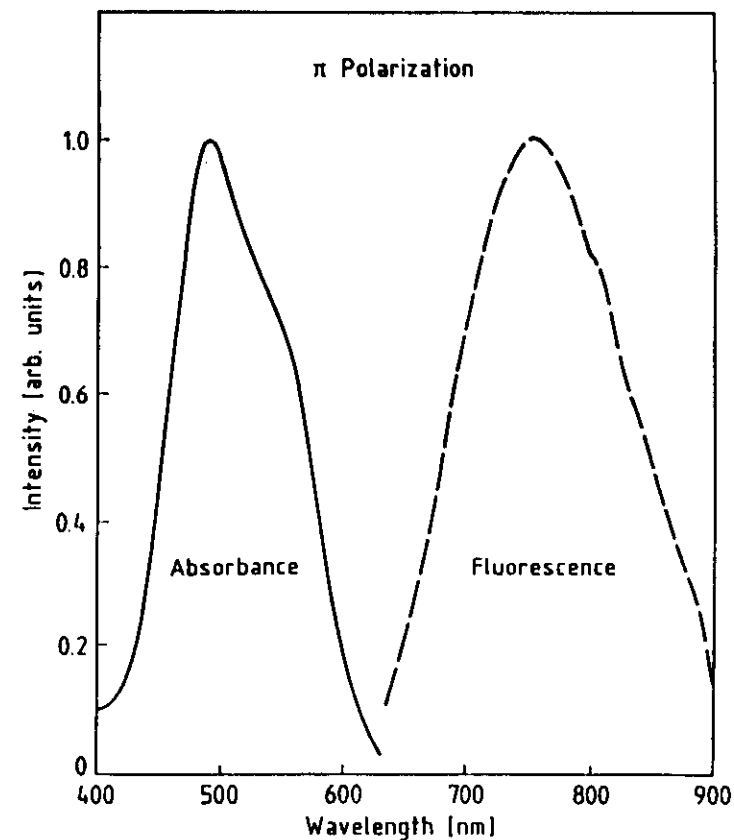
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LASER PROPERTIES OF ALEXANDRITE

Chemical formula	Cr:BeAl ₂ O ₄
Cr doping	0.3 %
Emission wavelengths	700-818 nm
Fluorescent lifetime	0.26 ms
Emission linewidth	100 nm
Quantum efficiency	70 %
Refractive index	1.74
Thermal conductivity	0.23 W/cm/K

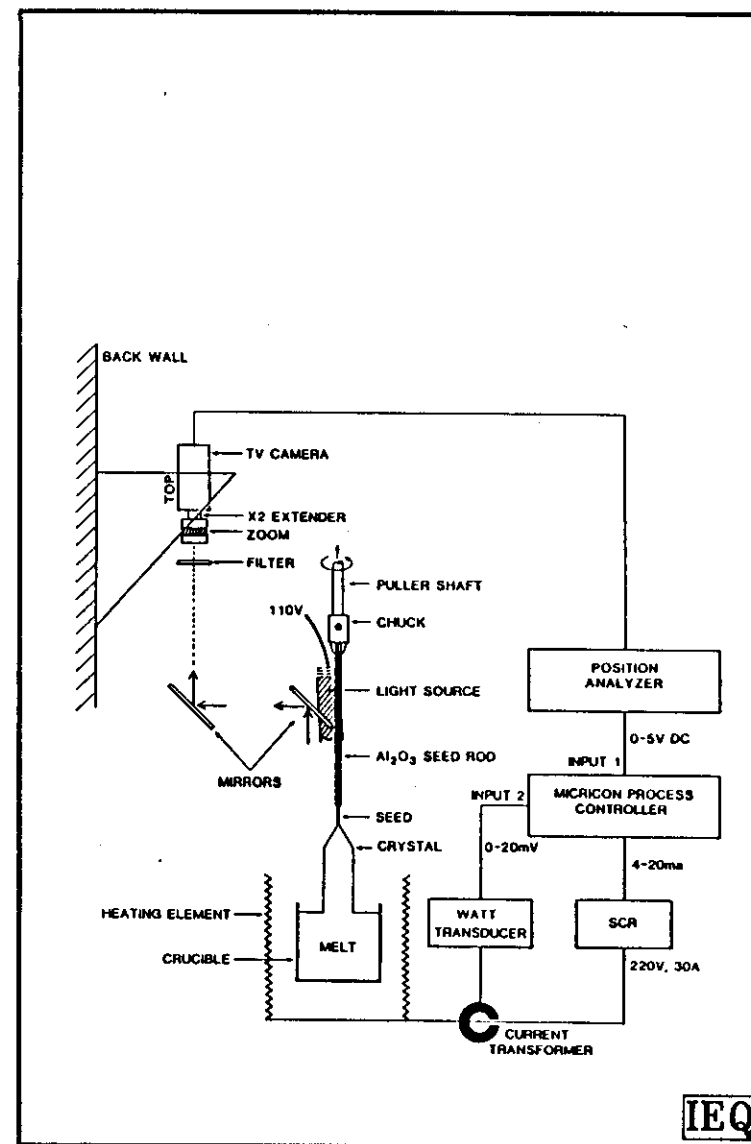
ABSORPTION AND FLUORESCENCE OF Ti:SAPPHIRE



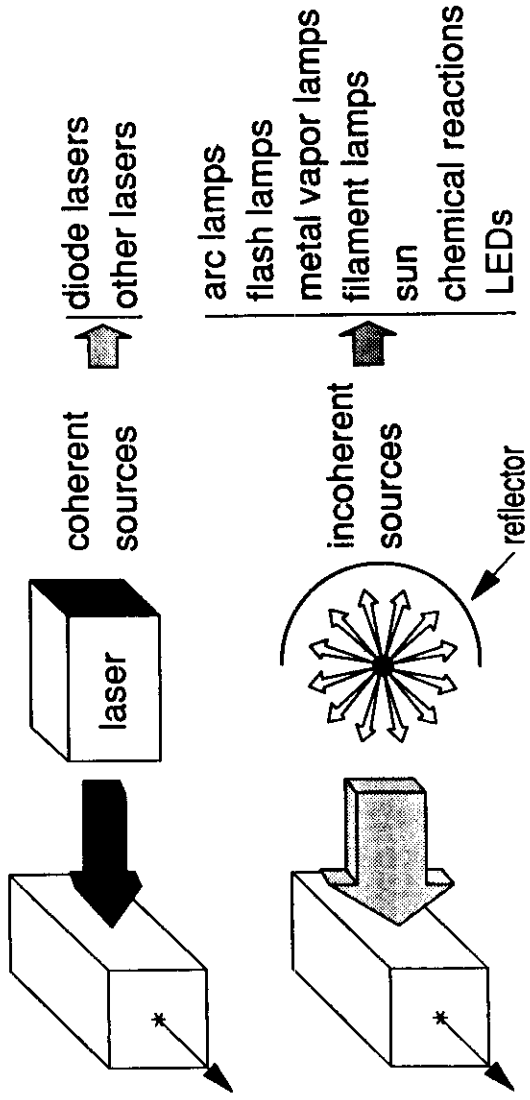
LASER PROPERTIES OF Ti:SAPPHIRE

Chemical formula	$\text{Ti:Al}_2\text{O}_3$
Ti doping	0.2 %
Emission wavelengths	650-1200 nm
Fluorescent lifetime	$3.2 \mu\text{s}$
Emission linewidth	120 nm
Quantum efficiency	100 %
Refractive index	1.76
Thermal conductivity	0.5 W/cm/K

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PUMPING SOURCES



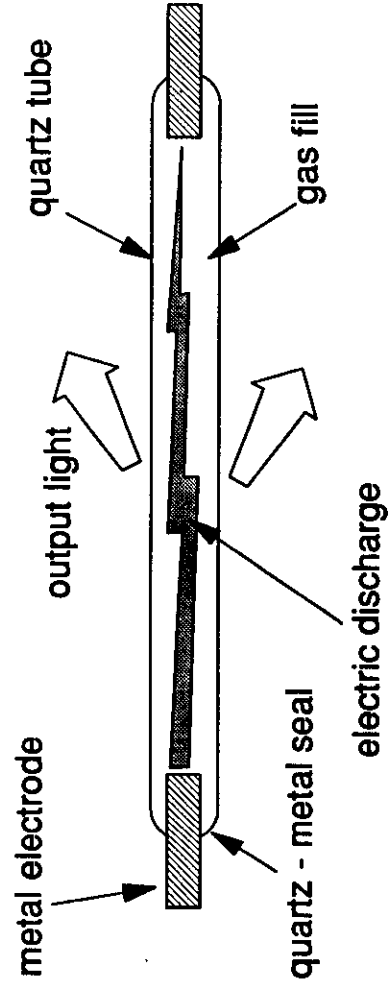
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PUMPING LAMPS OVERVIEW

SHAPE	EMITTER	COOLING	POWER	ARC
linear	noble gas	water →	300 W/cm ²	wall stabilized
helical	mercury	forced gas →	50 W/cm ²	vortex stabilized
point	alkaly metals	convection →	25 W/cm ²	
	tungsten halogen			

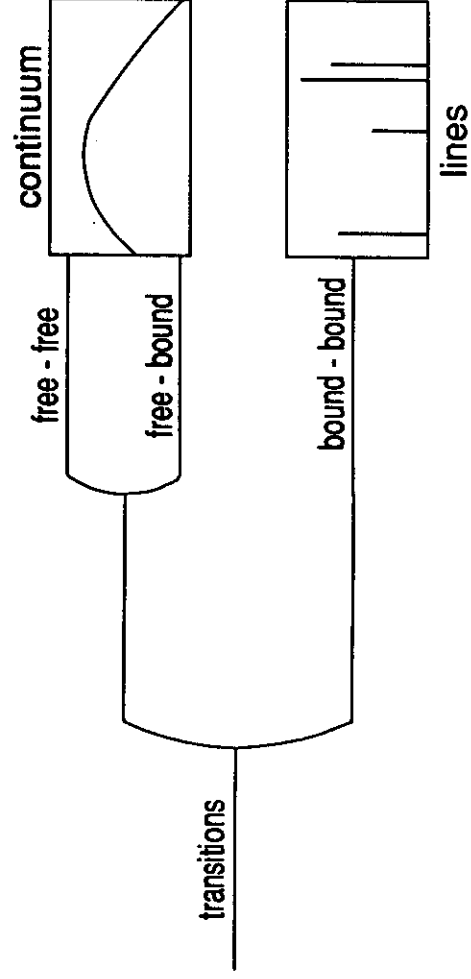
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LINEAR ARC LAMP



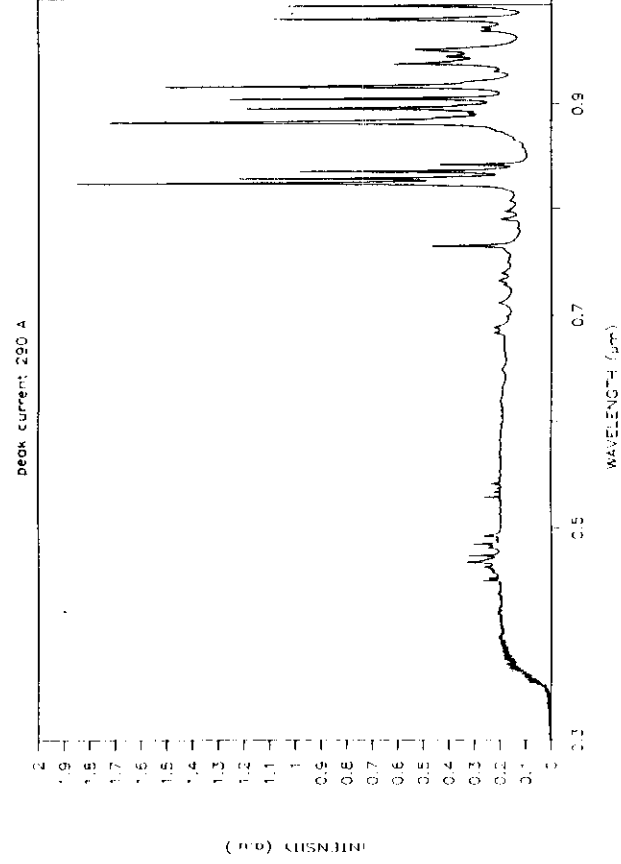
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SPECTRAL COMPONENTS

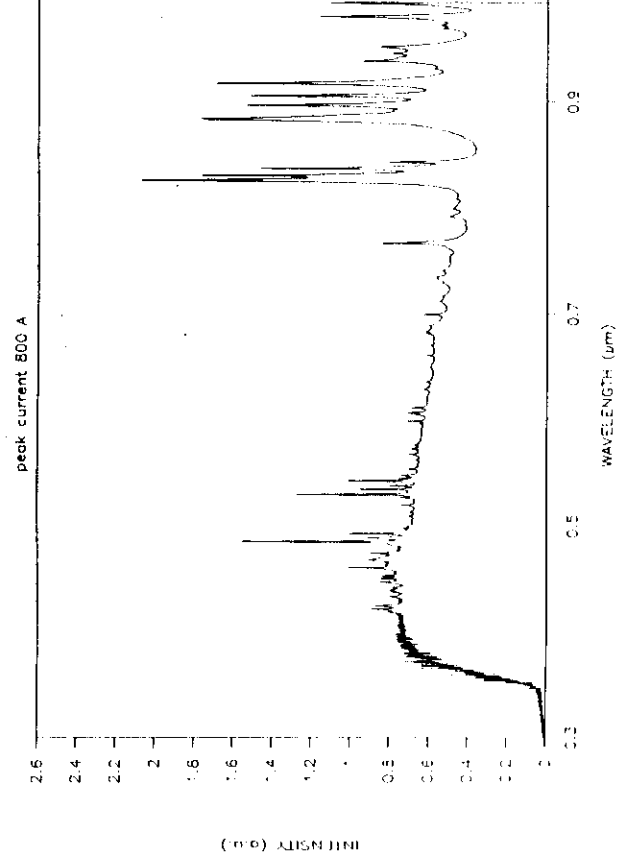


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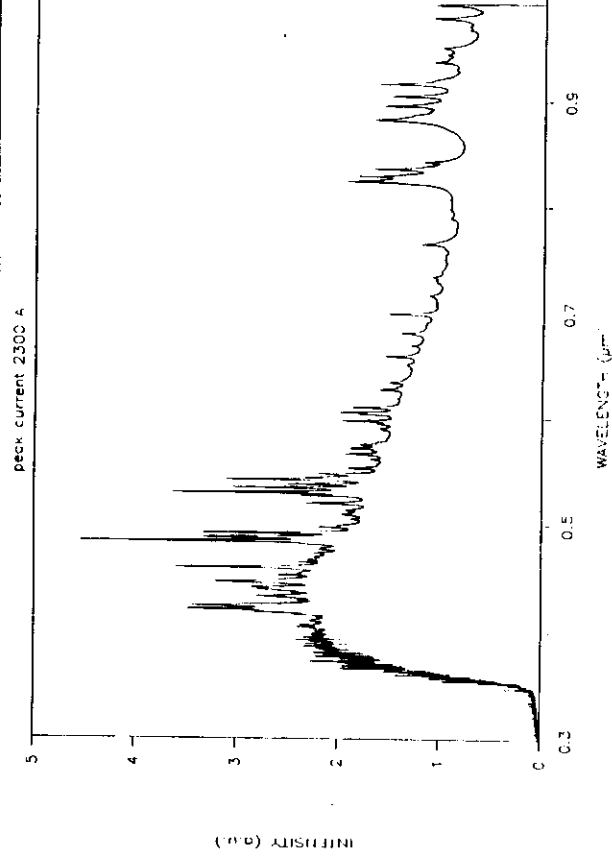
FLASHLAMPS EMISSION SPECTRA



FLASHLAMPS EMISSION SPECTRA

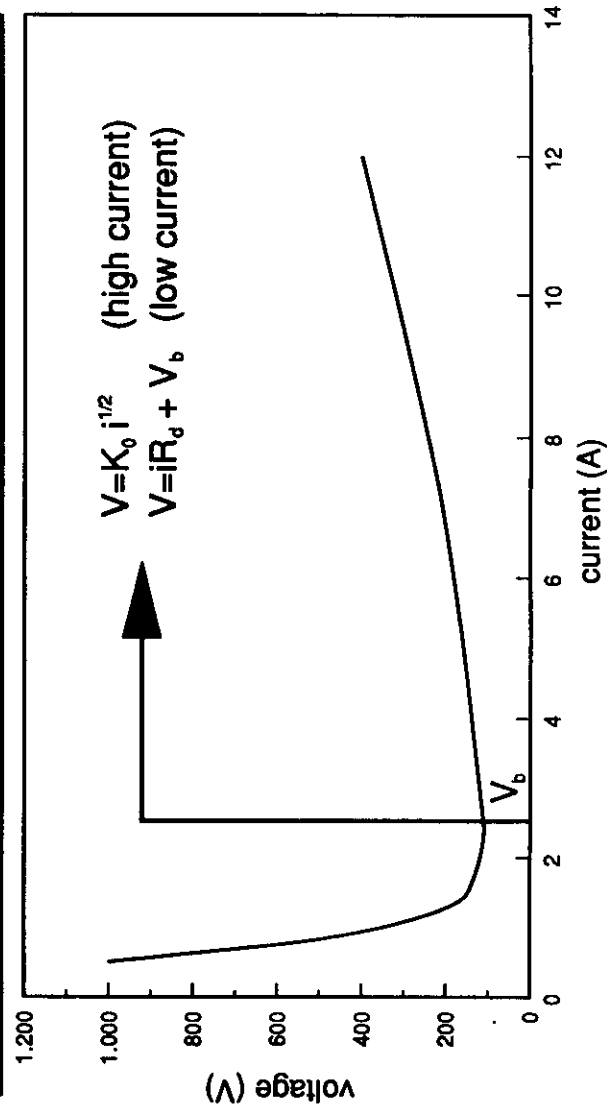


FLASHLAMPS EMISSION SPECTRA



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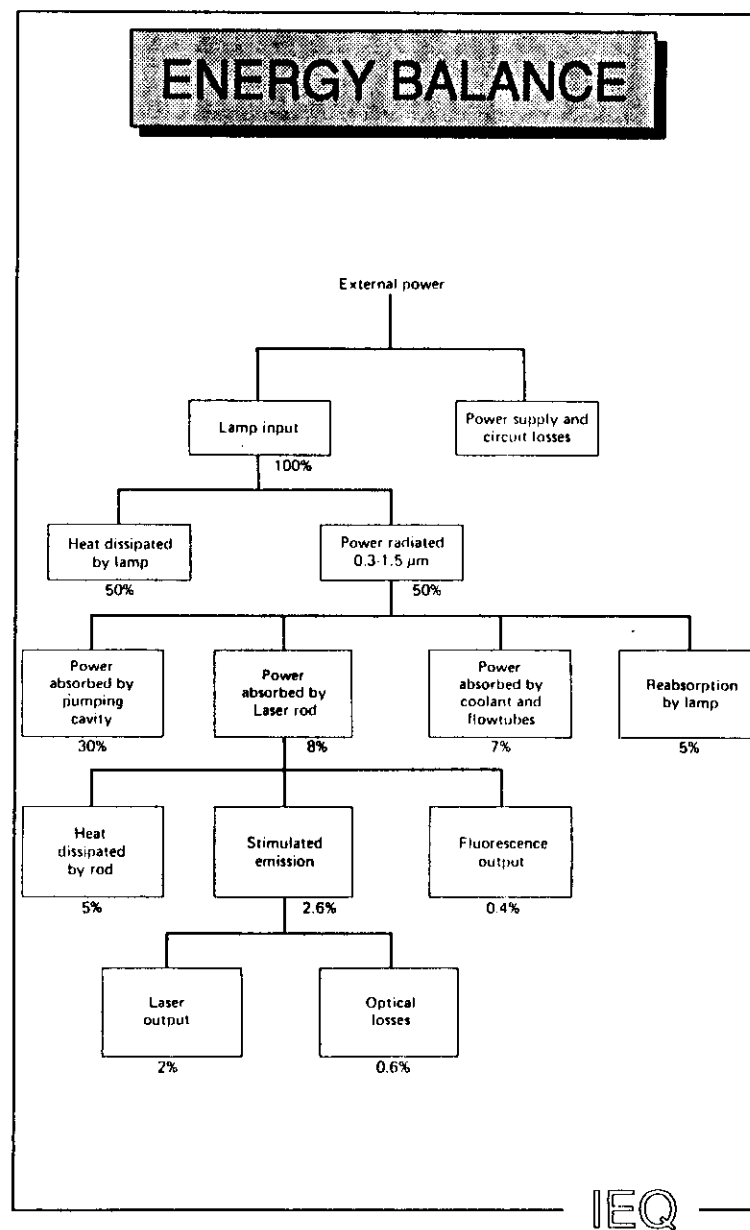
ELECTRICAL CHARACTERISTIC OF AN ARC LAMP



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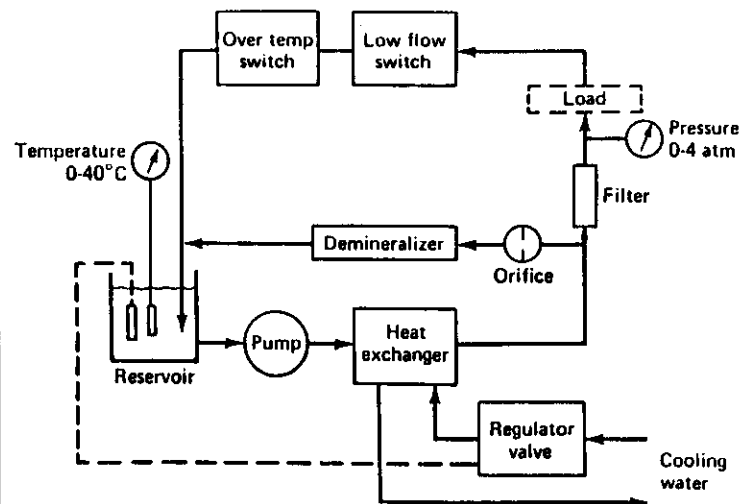
POWER SUPPLY FOR ARC LAMPS

The diagram illustrates a power supply system for arc lamps, featuring two main power sources and a triggering mechanism. A D.C. POWER SUPPLY provides a voltage V_m to the positive terminal of an INTERMEDIATE BOOST POWER SUPPLY. The negative terminal of this intermediate supply is connected to ground. The output of the intermediate supply is connected to a network of components: a series combination of an INTERMEDIATE CAPACITOR (C) and a resistor, followed by a series combination of a resistor and a diode. This network is connected to the primary of a BOOST POWER SUPPLY. The secondary of the boost supply is connected to the positive terminal of the ANODE (RED) of an arc lamp. The negative terminal of the arc lamp is connected to ground. A TRIGGER PULSE GENERATOR is connected to the primary of a transformer, which is in series with the primary of the boost supply. A diode is connected in parallel with the primary of the boost supply. A capacitor labeled $\sim 1 \mu f$ is connected between the positive terminal of the arc lamp and the positive terminal of the boost supply. The output voltage of the boost supply is labeled V_o . The intermediate capacitor is labeled C, and the intermediate resistor is labeled R. The output voltage of the D.C. supply is labeled V_m . The output voltage of the intermediate supply is labeled V_i . The output voltage of the boost supply is labeled V_o . The output voltage of the arc lamp is labeled ANODE (RED).



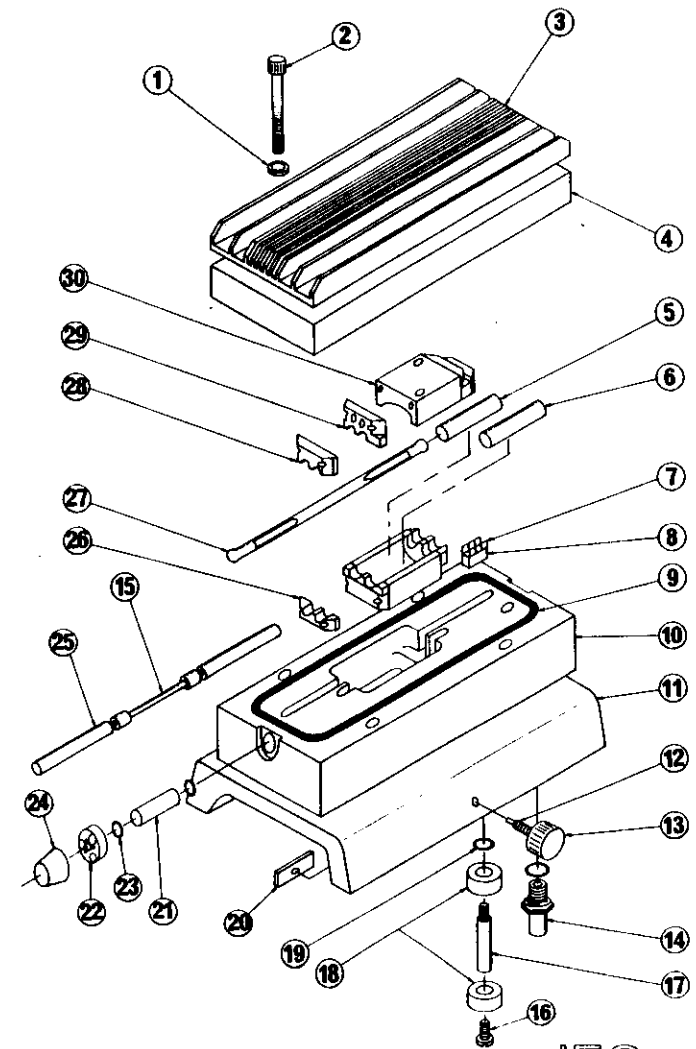
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WATER COOLING SYSTEM



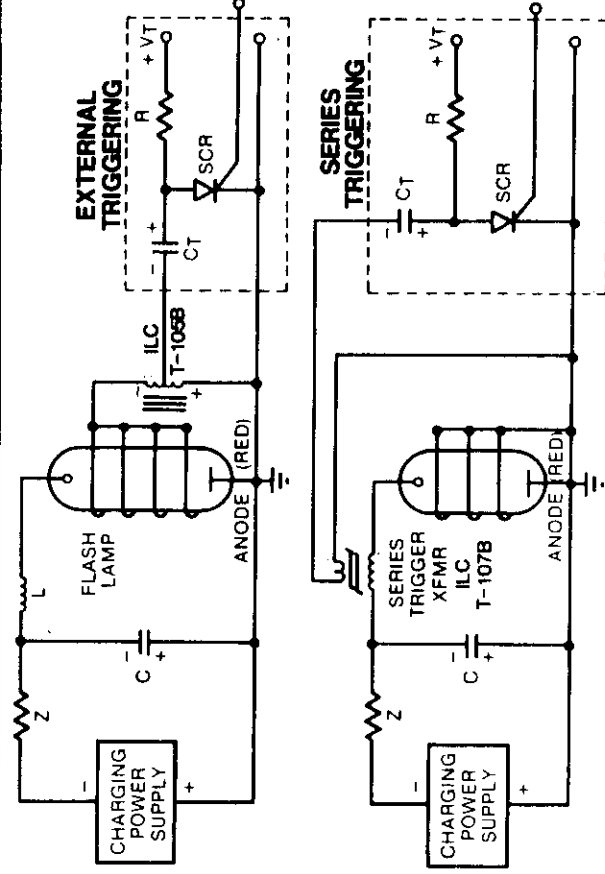
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CW Nd:YAG LASER



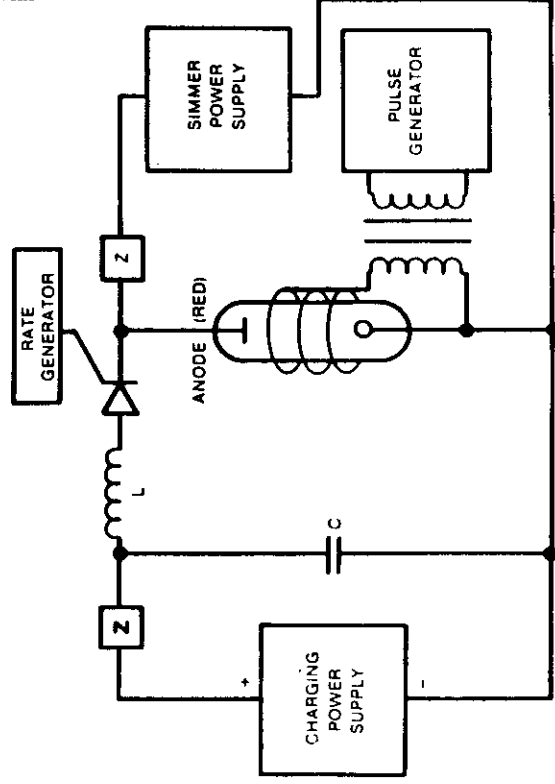
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FLASHLAMP DISCHARGE CIRCUITS



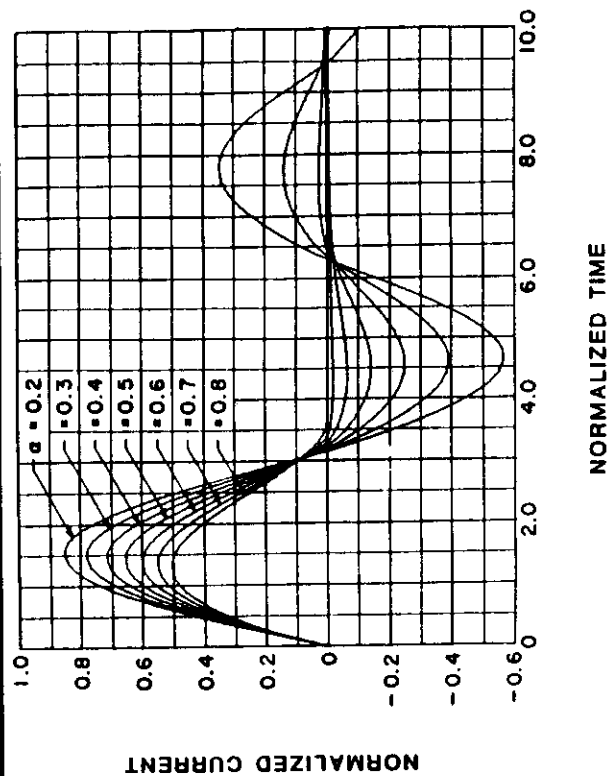
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SIMMER POWER SUPPLY



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FLASHLAMPS DAMPING PARAMETER



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DISCHARGE CIRCUIT CALCULATIONS

Assumptions:

- ☐ Constant lamp impedance during the pulse
- ☐ Pulse durations from 30 μ s to 10 ms
- ☐ $V = K_0 I^{1/2}$

$$C^3 = \frac{2E_0 \alpha_4 t_2}{K_0^4}$$

$$L = \frac{t^2}{C}$$

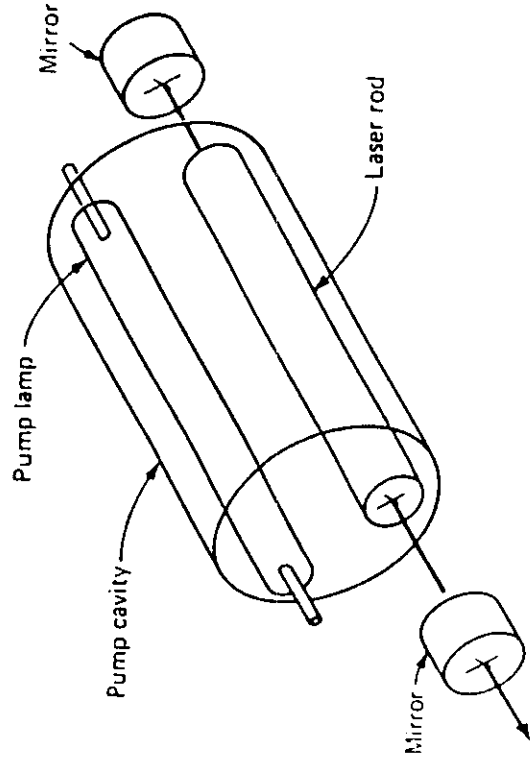
$$V_0 = (2E_0/C)^{1/2}$$

Where:

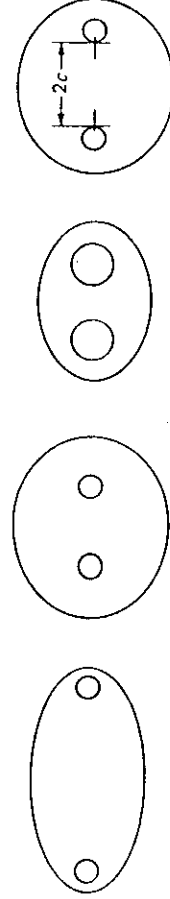
- E_0 = storage energy (Joules)
- L = total inductance (henries)
- C = capacitance (farad)
- t = 1/3 pulse width (seconds)
- K_0 = impedance parameter
- V_0 = capacitor voltage (volts)
- α = damping factor (0.8)

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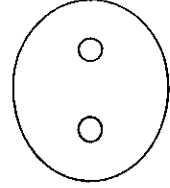
COMPONENTS OF A LAMP PUMPED LASER



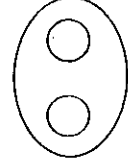
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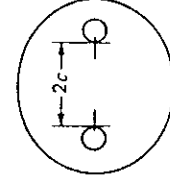
(a) Single ellipse with large eccentricity



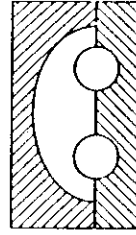
(b) Small eccentricity



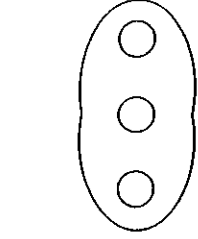
(c) Closed coupled



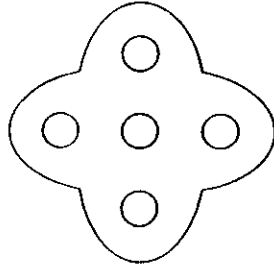
(d) Ex focal



(e) Semi ellipse



(f) Double ellipse

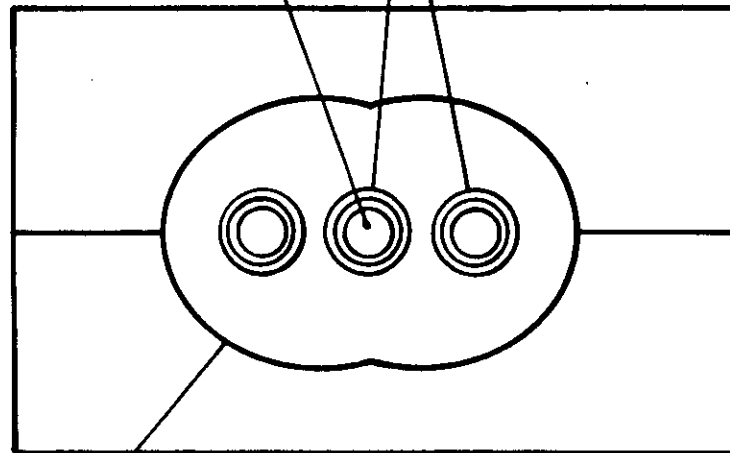


(g) Multi elliptical cavity

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DOUBLE ELLIPSE REFLECTIVE CAVITY

YAG ROD FLOW TUBES

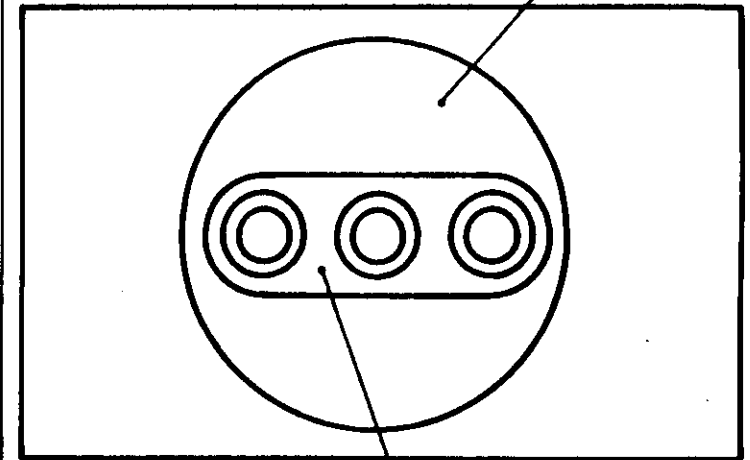


REFLECTIVE COATING

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CLOSE COUPLED DIFFUSIVE CAVITY

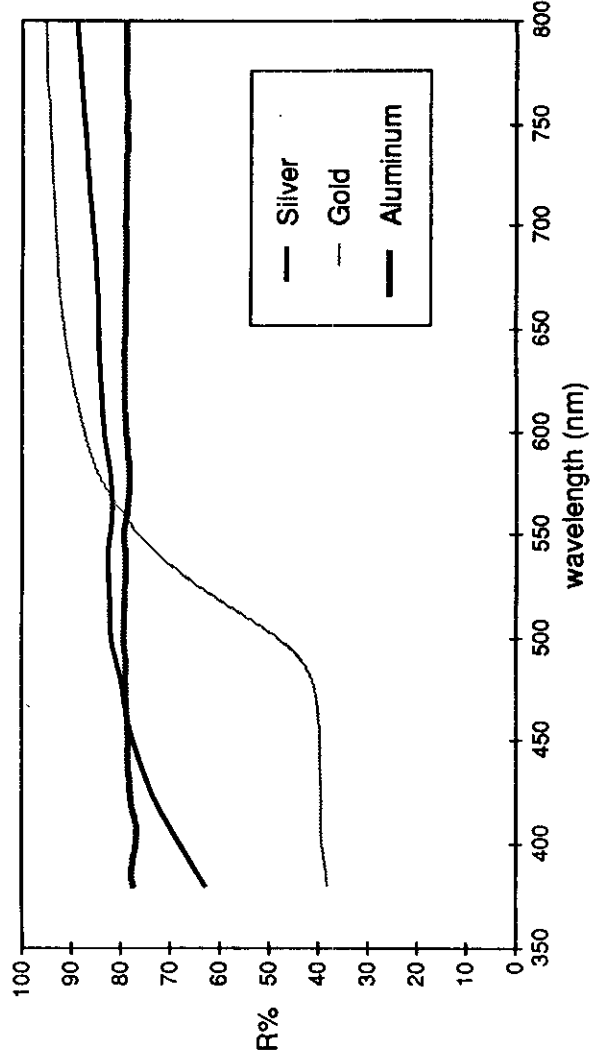
MgO OR BaSO₄ COMPRESSED
POWDER OR CERAMIC MATERIAL



GLASS CLADDING

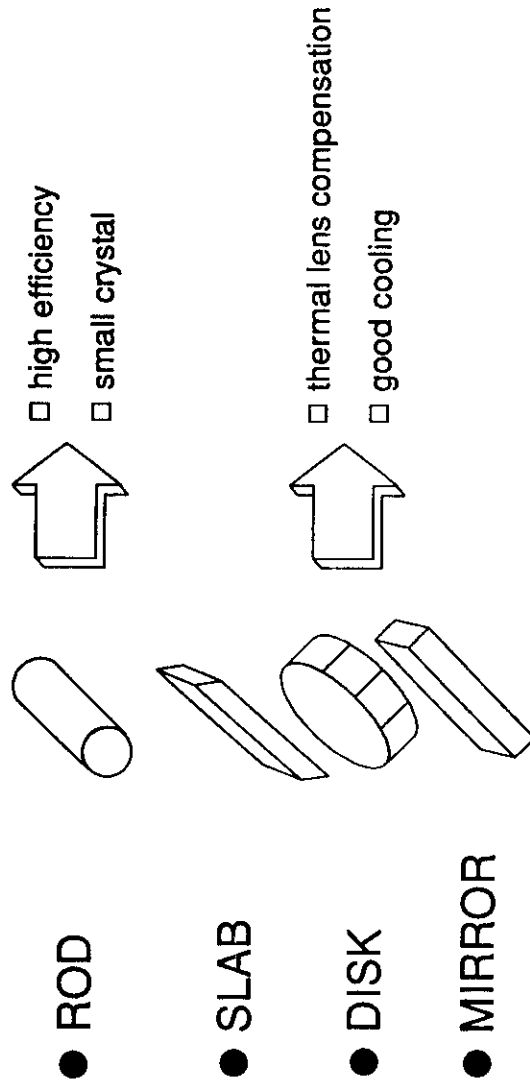
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REFLECTIVITY OF METALLIC COATINGS



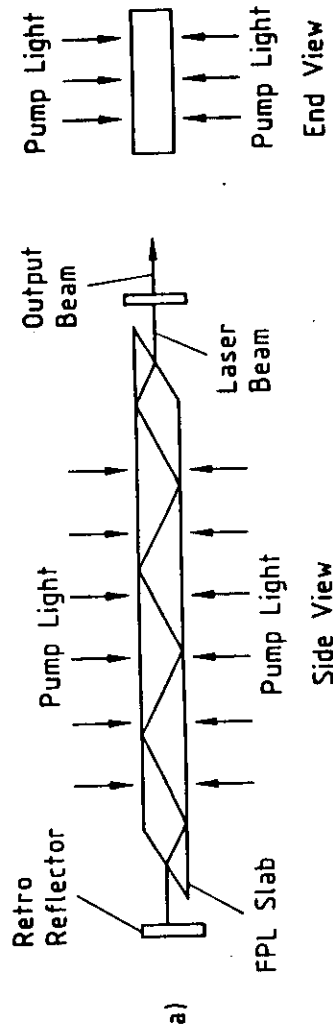
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CRYSTAL GEOMETRIES



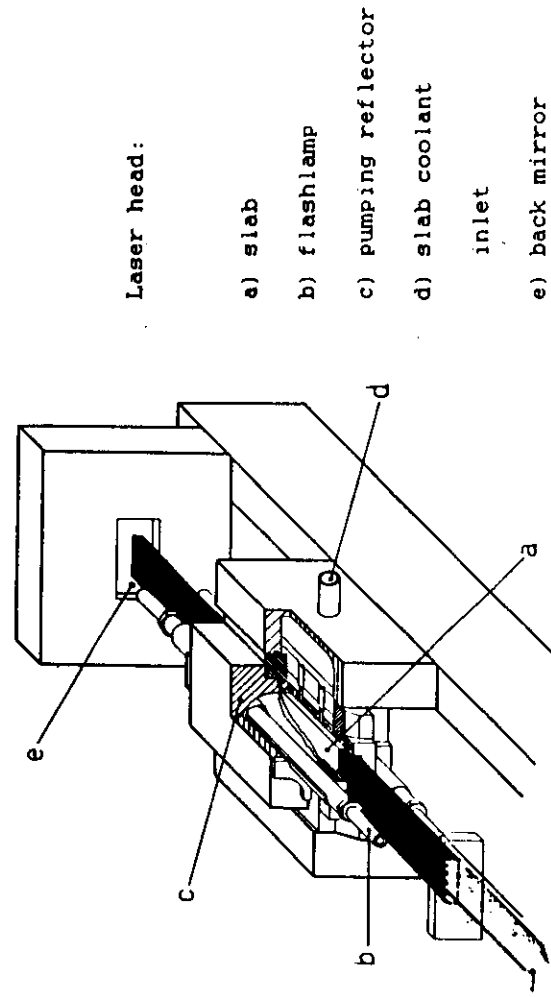
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ZIG-ZAG SLAB LASER



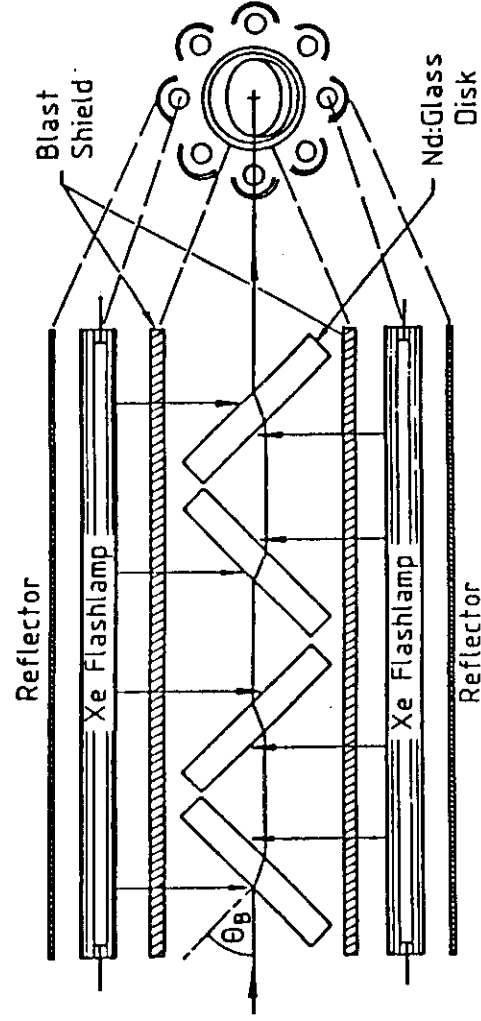
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ZIG-ZAG SLAB LASER



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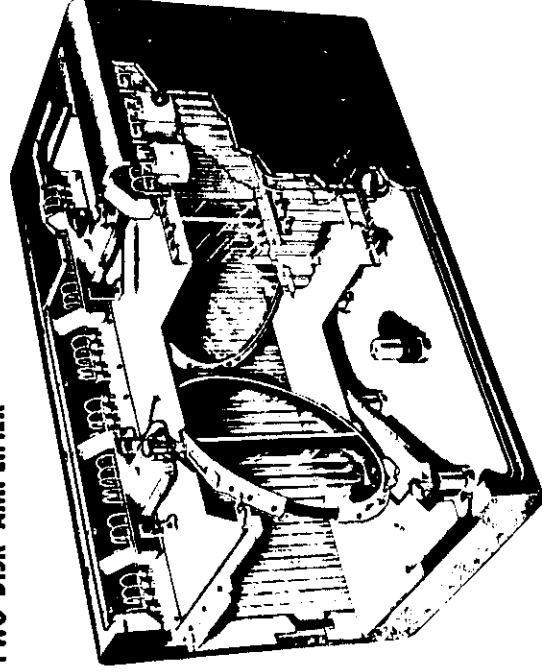
DISK AMPLIFIER



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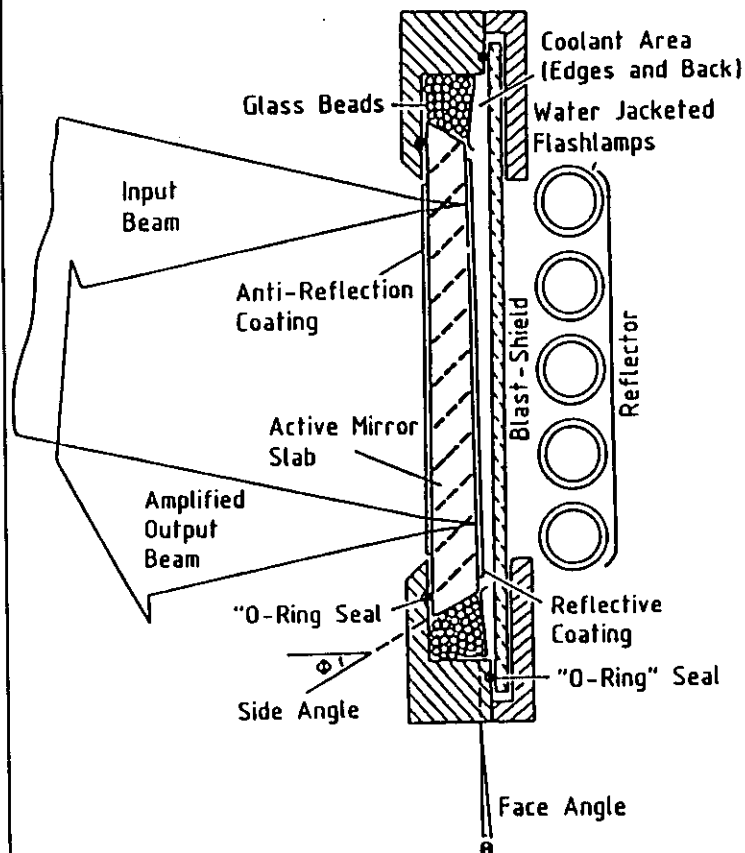
DISK AMPLIFIER

46cm TWO DISK AMPLIFIER



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ACTIVE MIRROR AMPLIFIER



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SEMICONDUCTOR LASER PUMPING

● ADVANTAGES:

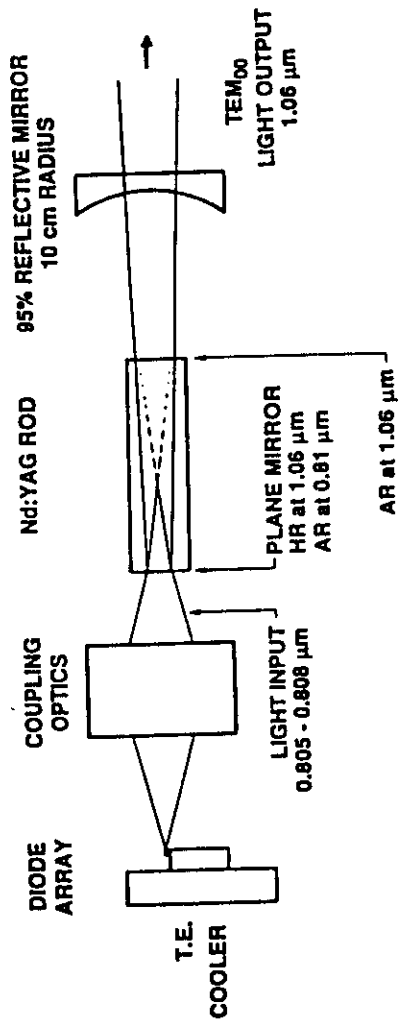
- ☐ high transfer and overall efficiency
- ☐ system lifetime and reliability
- ☐ low voltage operation
- ☐ compactness and ruggedness
- ☐ good beam quality (TEM 00)
- ☐ output peak peak power (Q-switch)
- ☐ emission wavelength and linewidth

● DISADVANTAGES

- ☐ very high cost / watt
- ☐ low power available
- ☐ complicated pumping arrangement

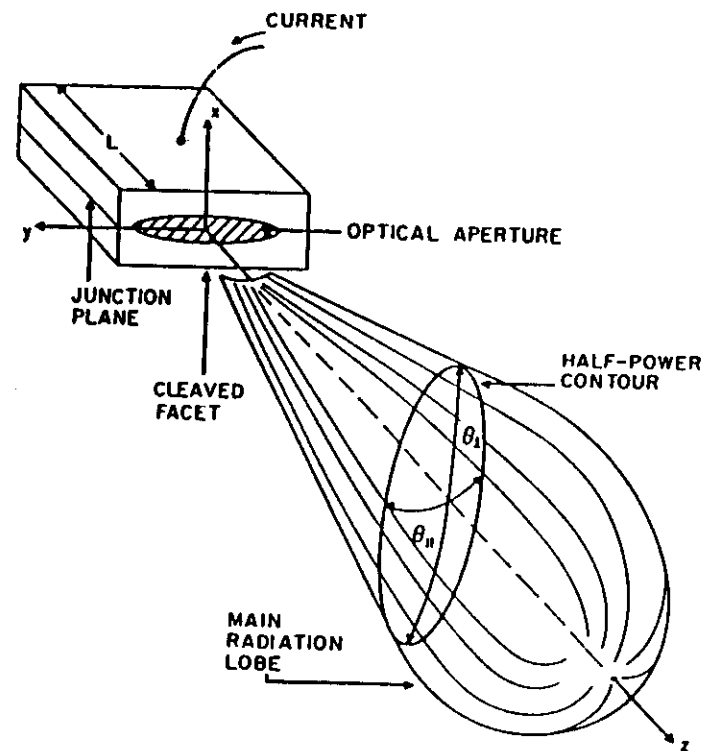
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RESONATORS PARAMETERS



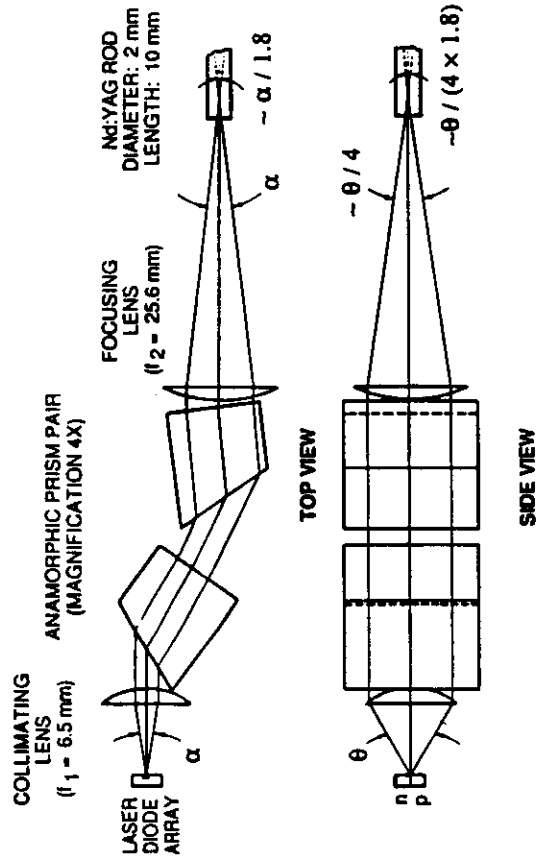
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RADIATION PATTERN FROM A SEMICONDUCTOR LASER



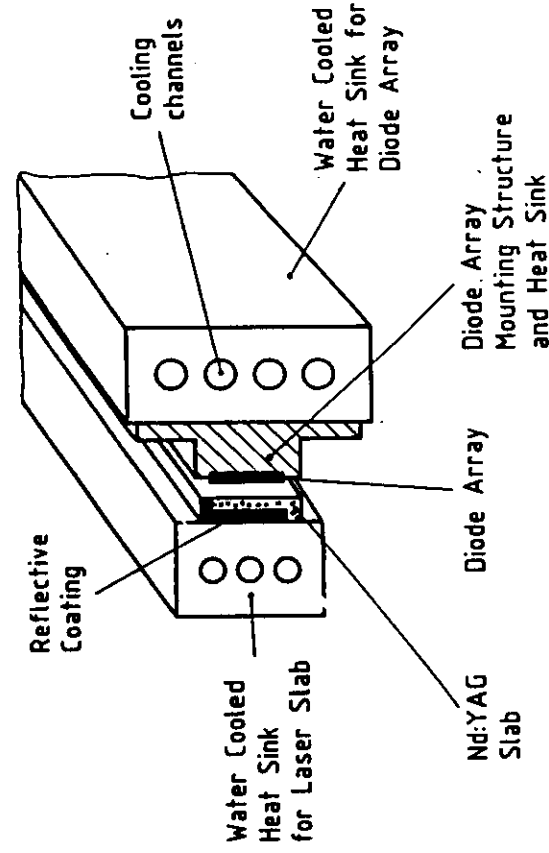
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DIODE ARRAY COUPLING OPTICS



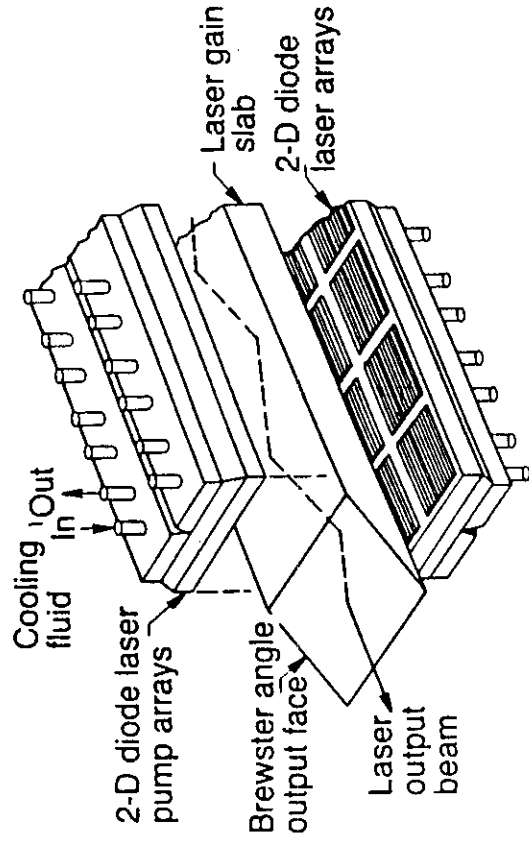
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LASER-DIODE-PUMPED SLAB



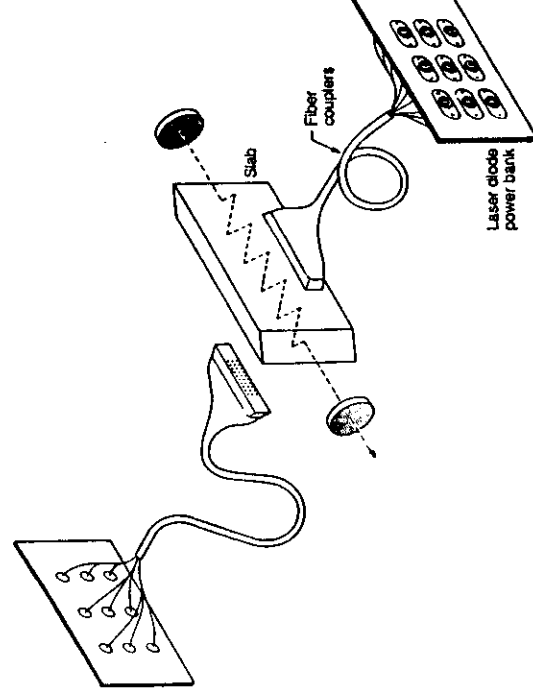
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SEMICONDUCTOR LASER PUMPED SLABS



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SEMICONDUCTOR LASER PUMPED SLABS



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COST OF TEM₀₀ LASERS

